

## Discrete POWER & Signal **Technologies**

# FDH / FDLL 600





LL-34 THE PLACEMENT OF THE EXPANSION GAP HAS NO RELATIONSHIP TO THE LOCATION OF THE CATHODE TERMINAL

**COLOR BAND MARKING** DEVICE 1ST BAND 2ND BAND FDLL600 RED WHITE

High Conductance Ultra Fast Diode  Sourced from Process 1R. See MMBD1201-1205 for characteristics.  Absolute Maximum Ratings*  TA = 25°C unless otherwise noted					
Symbol	Parameter	Value	Units		
W <sub>IV</sub>	Working Inverse Voltage	50	V		
Io	Average Rectified Current	200	mA		
I <sub>F</sub>	DC Forward Current	400	mA		
i <sub>f</sub>	Recurrent Peak Forward Current	600	mA		
İf(surge)	Peak Forward Surge Current Pulse width = 1.0 second Pulse width = 1.0 microsecond	1.0 4.0	A A		
T <sub>stg</sub>	Storage Temperature Range	-65 to +200	°C		
TJ	Operating Junction Temperature	175	°C		

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

## NOTES:

- 1) These ratings are based on a maximum junction temperature of 200 degrees C.

  2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		FDH/FDLL 600	
P <sub>D</sub>	Total Device Dissipation	500	mW
	Derate above 25°C	3.33	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W

# **High Conductance Ultra Fast Diode**

(continued)

## **Electrical Characteristics**

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
B <sub>V</sub>	Breakdown Voltage	$I_R = 5.0  \mu A$	75		V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 50 V V <sub>R</sub> = 50 V, T <sub>A</sub> = 150°C		100 100	nA μA
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 1.0 mA I <sub>F</sub> = 10 mA I <sub>F</sub> = 50 mA I <sub>F</sub> = 100 mA I <sub>F</sub> = 200 mA		650 790 860 920 1.0	mV mV mV mV
Co	Diode Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		2.5	pF
$T_RR$	Reverse Recovery Time	$\begin{aligned} I_F &= I_R = 10 \text{ mA}, \ I_{ff} = 1.0 \text{ mA}, \\ R_L &= 100 \ \Omega \\ I_F &= I_R = 200 \text{ mA}, \ I_{ff} = 20 \text{ mA}, \\ R_L &= 100 \ \Omega \end{aligned}$		4.0 6.0	nS nS



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